

30V Dual P-Channel Enhancement MOSFET

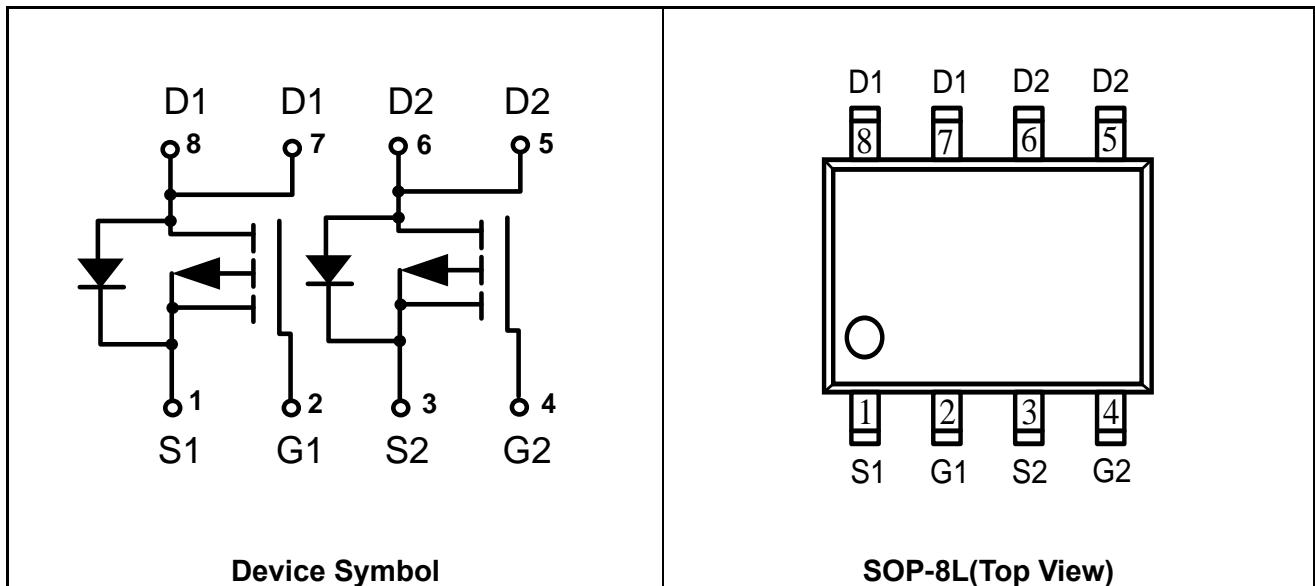
Features

- $V_{DS} = -30V$, $I_D = -5A$
 $R_{DS(on)} < 60m\Omega$ @ $V_{GS} = -10V$
 $R_{DS(on)} < 90m\Omega$ @ $V_{GS} = -4.5V$
- Trench Power LV MOSFET Technology

Mechanical Characteristics

- SOP-8L Package
- Marking : Making Code
- RoHS Compliant

Schematic & PIN Configuration



EM03DP50A

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ⁽¹⁾	I_D	-5	A
Total Power Dissipation	P_D	2.3	W
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance from Junction to Ambient ⁽²⁾	$R_{\theta JA}$	54.3	$^\circ\text{C/W}$

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Electrical Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V_{BDSS}	$V_{GS} = 0\text{V}, I_D = -250\mu\text{A}$	-30	-	-	V
Gate-body Leakage current	I_{GSS}	$V_{DS} = 0\text{V}, V_{GS} = \pm 20\text{V}$	-	-	± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -30\text{V}, V_{GS} = 0\text{V}$	-	-	-1	μA
Gate-Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = -250\mu\text{A}$	-1.0	-1.5	-2.1	V
Drain-Source On-Resistance ⁽³⁾	$R_{DS(on)}$	$V_{GS} = -10\text{V}, I_D = -4.1\text{A}$	-	42	60	$\text{m}\Omega$
		$V_{GS} = -4.5\text{V}, I_D = -3\text{A}$	-	57	90	
Dynamic Characteristics ⁽⁴⁾						
Input Capacitance	C_{iss}	$V_{DS} = -15\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$	-	530	-	pF
Output Capacitance	C_{oss}		-	70	-	
Reverse Transfer Capacitance	C_{rss}		-	56	-	
Switching Characteristics ⁽⁴⁾						
Total Gate Charge	Q_g	$V_{GS} = -10\text{V}, I_D = -4.1\text{A}, V_{DS} = -15\text{V}$	-	10	-	nC
Gate-Source Charge	Q_{gs}		-	2	-	
Gate-Drain Charge	Q_{gd}		-	2.8	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{GS} = -10\text{V}, V_{DD} = -15\text{V}, R_G = 6\Omega, I_D = -4.1\text{A}$	-	6.9	-	ns
Rise Time	t_r		-	12	-	
Turn-Off Delay Time	$t_{d(off)}$		-	19	-	
Fall Time	t_f		-	7.5	-	
Source-Drain Body Diode Characteristics						
Diode Forward Voltage ⁽³⁾	V_{SD}	$I_S = -1.7\text{A}, V_{GS} = 0\text{V}$	-	-	-1.2	V
Continuous Source Current	I_S		-	-	-5	A

Note1: Repetitive rating, pulse width limited by junction temperature $T_{J(\text{MAX})}=150^\circ\text{C}$

Note2: The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper, The value in any given application depends on the user's specific board design.

Note3: Pulse Test: Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

Note4: This value is guaranteed by design hence it is not included in the production test.

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Typical Characteristics

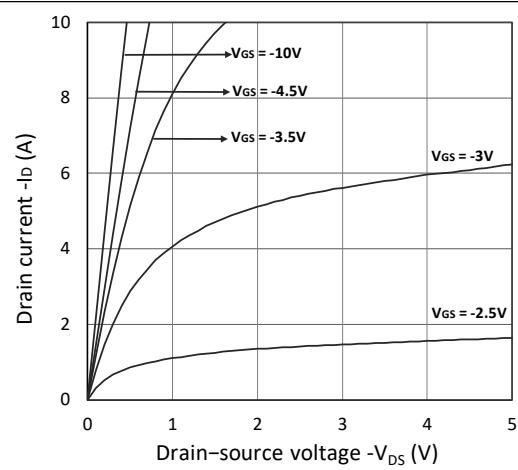


Figure 1. Output Characteristics

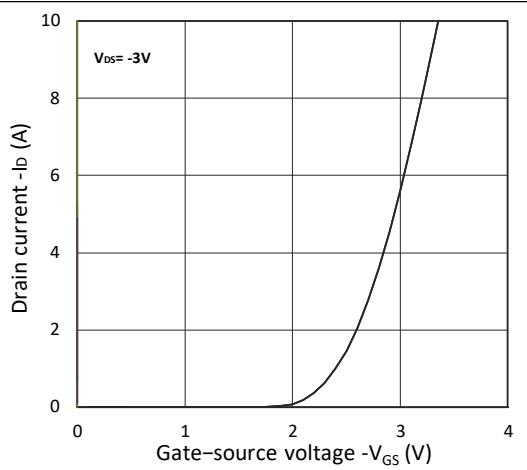


Figure 2. Transfer Characteristics

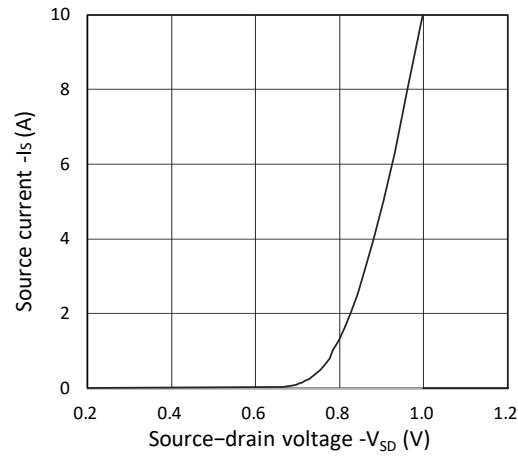


Figure 3. Forward Characteristics of Reverse

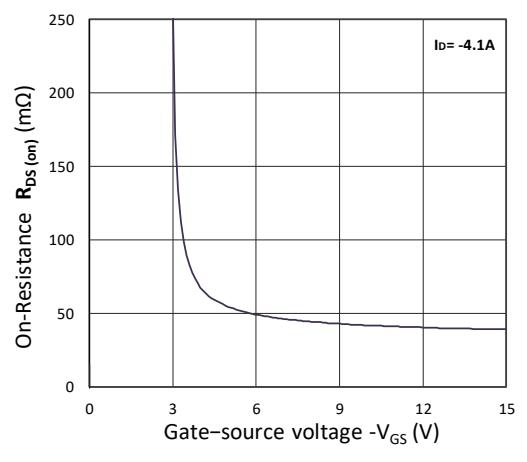


Figure 4. $R_{DS(ON)}$ vs. V_{GS}

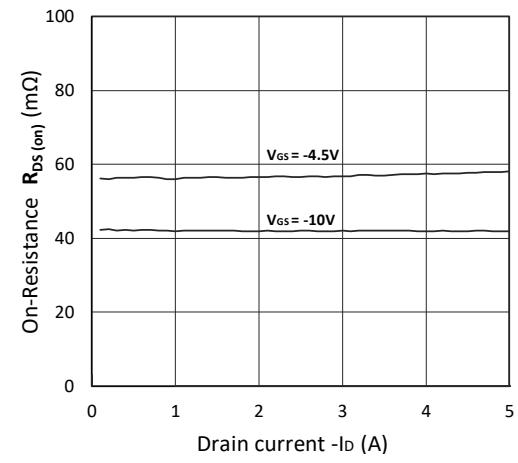


Figure 5. $R_{DS(ON)}$ vs. I_D

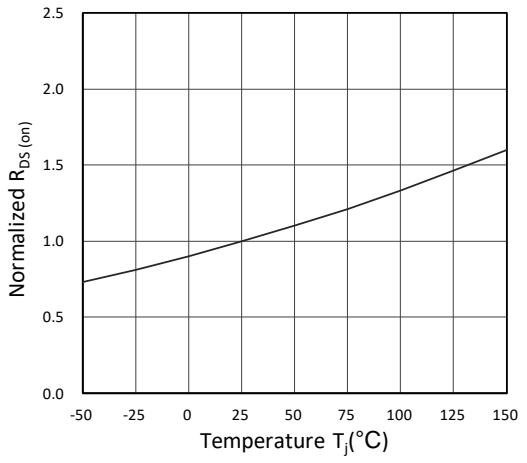
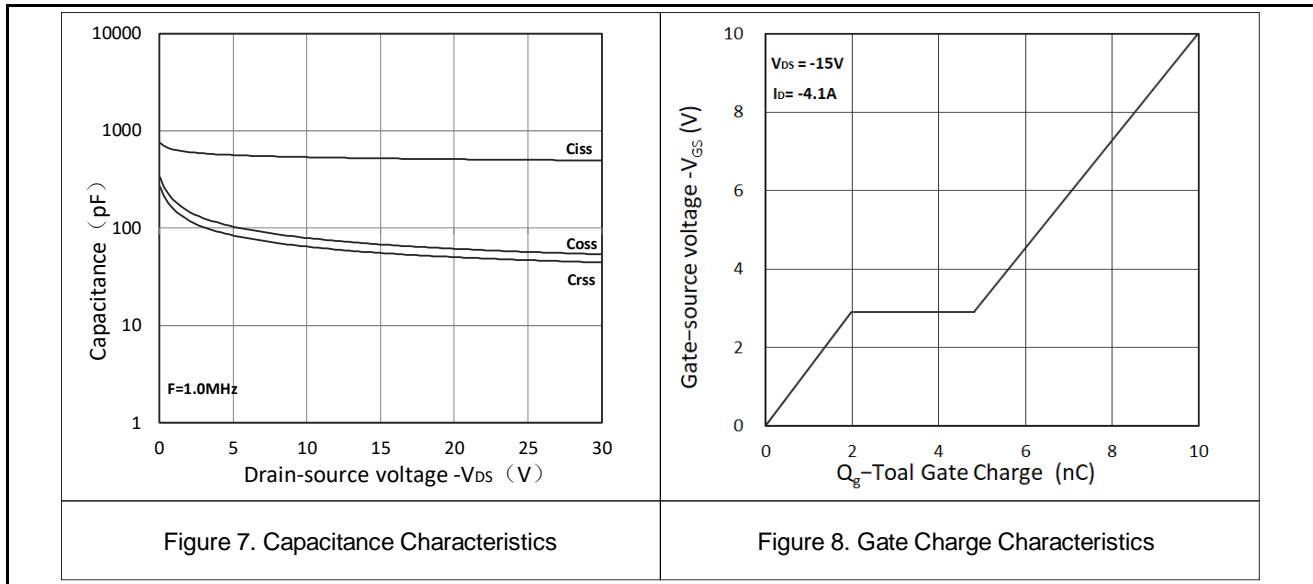


Figure 6. Normalized $R_{DS(ON)}$ vs. Temperature

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Typical Characteristics(Continued)



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Package Dimension

SOP-8L

SYMBOL	MILLIMETER	
	MIN	MAX
A	1.35	1.75
a1	0.05	0.25
b	0.31	0.51
b1	0.16	0.25
D	4.70	5.15
E	5.75	6.25
e	1.07	1.47
F	3.70	4.10
L	0.40	1.27

PACKAGE OUTLINE

The diagram illustrates the package outline for an SOP-8L package. It shows a top-down view of the package body with pins at the bottom and a side cross-sectional view of the lead. Key dimensions are labeled: A (height), b (width of the body), e (lead thickness), D (body width), E (body height), F (body thickness), b1 (lead pitch), a1 (lead lead-in length), L (lead lead-out length), and the lead angle of 8°.

EM03DP50A

Ordering Information

Part	Package	Marking	Packing Information
EM03DP50A	SOP-8L	4953	4k/Reel

Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2018-08-07	Released Version	Qi Shu Kun	Qi Shu Kun	Liu Jia Ying